L=36, Nfin=2, ULVT, stress (HCI: VG=1.8, VD=2.0, 0.2s x 12) after charge pumping (g) vs Block erase VG=0, VDBS=2.4, 10x1min (m), reversed IDS-VGS curves 100 80 IDS (uA) 60 40 20

0.5

VGS (V)

0.4

0.7

8.0

0.6

0.2

0.3